

# **GL480E00000F**

# **Infrared Emitting Diode**



#### **■** Features

- 1. Side view emission type
- 2. Plastic mold with resin lens
- 3. Medium directivity angle ( $\Delta\theta$ : ±13° TYP.) Peak emission wavelength: 950 nm TYP.
- 4. Radiant flux be: 0.7 mW MIN.
- 5. Lead free and RoHS directive component

## ■ Agency Approvals/Compliance

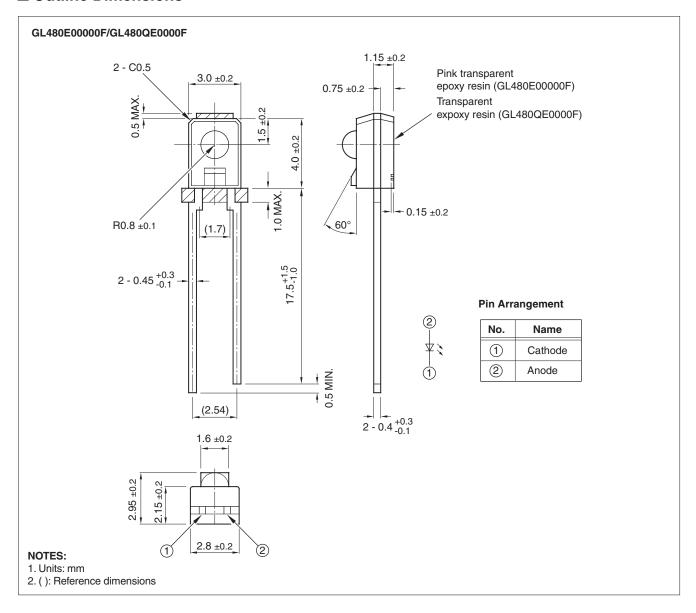
- 1. Compliant with RoHS directive (2002/95/EC)
- 2. Content information about the six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (popular name: China RoHS) (Chinese: 电子信息产品污染控制管理办法); refer to page 7

## ■ Applications

- 1. Office automation equipment
- 2. Audio visual equipment
- 3. Home appliances
- 4. Telecommunication equipment
- 5. Measuring equipment
- 6. Tooling machines
- 7. Computers



#### **■** Outline Dimensions





## ■ Absolute Maximum Ratings

(Ta = 25°C)

| Parameter                | Symbol          | Rating     | Unit |
|--------------------------|-----------------|------------|------|
| Forward current          | I <sub>F</sub>  | 50         | mA   |
| Peak forward current *1  | I <sub>FM</sub> | 1          | Α    |
| Reverse voltage          | $V_{R}$         | 6          | V    |
| Power dissipation        | Р               | 75         | mW   |
| Operating temperature    | Topr            | -25 to +85 | °C   |
| Storage temperature      | Tstg            | -40 to +85 | °C   |
| Soldering temperature *2 | Tsol            | 260        | °C   |
|                          |                 |            |      |

<sup>\*1</sup> Pulse width: 100 µs, Duty ratio: 0.01

# **■** Electro-optical Charactertistics

| Parameter                 | Symbol         | Conditions                    | MIN. | TYP. | MAX. | Unit    |
|---------------------------|----------------|-------------------------------|------|------|------|---------|
| Forward voltage           | V <sub>F</sub> | I <sub>F</sub> = 20 mA        | _    | 1.2  | 1.4  | V       |
| Peak forward voltage      | $V_{FM}$       | I <sub>FM</sub> = 0.5 A       | _    | 3.0  | 4.0  | V       |
| Reverse current           | I <sub>R</sub> | V <sub>R</sub> = 3 V          | _    | _    | 10   | μΑ      |
| Radiant flux              | Фе             | I <sub>F</sub> = 20 mA        | 0.7  | _    | 3.0  | mW      |
| Peak emission wavelength  | λр             | I <sub>F</sub> = 5 mA         | _    | 950  | _    | nm      |
| Half intensity wavelength | Δλ             | I <sub>F</sub> = 5 mA         | _    | 45   | _    | nm      |
| Terminal capacitance      | C <sub>t</sub> | V <sub>R</sub> = 0, f = 1 MHz | _    | 50   | _    | pF      |
| Response frequency        | f <sub>C</sub> | _                             | _    | 300  | _    | kHz     |
| Angle of half intensity   | Δθ             | I <sub>F</sub> = 20 mA        | _    | ±13  | _    | degrees |

Fig. 1 Forward Current vs.

Ambient Temperature

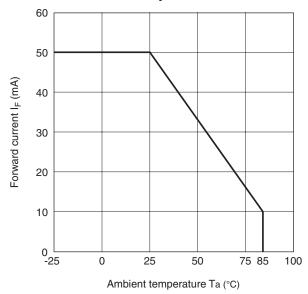
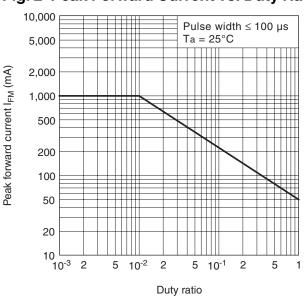


Fig. 2 Peak Forward Current vs. Duty Ratio



<sup>\*2 5</sup> s (MAX.) positioned 1.4 mm from the resin edge. See Figure 11.



Fig. 3 Spectral Distribution

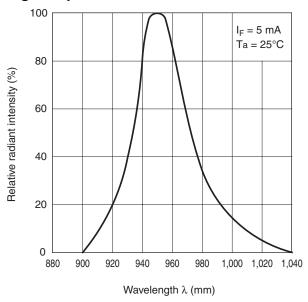


Fig. 4 Peak Emission Wavelength vs.
Ambient Temperature

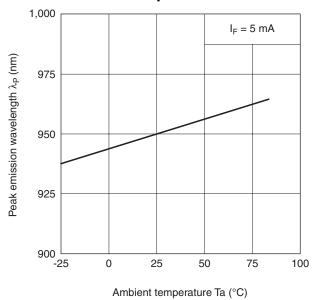


Fig. 5 Forward Current vs. Forward Voltage

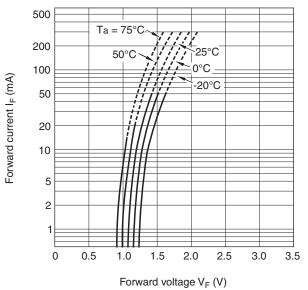


Fig. 6 Relative Radiant Flux vs.
Ambient Temperature

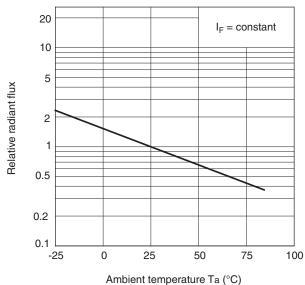




Fig. 7 Radiant Flux vs. Foward Current

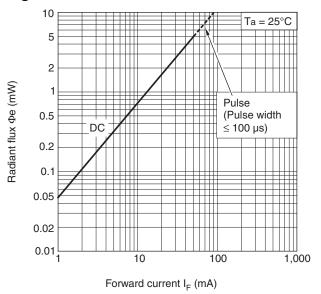


Fig. 8 Relative Radiant Intensity vs. Distance

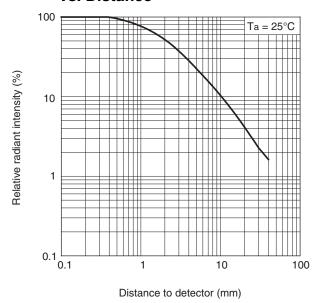


Fig. 9 Relative Collector Current vs. Distance

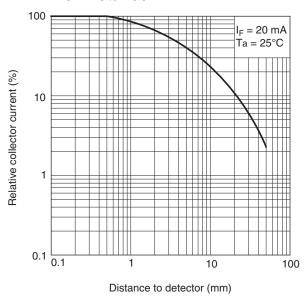
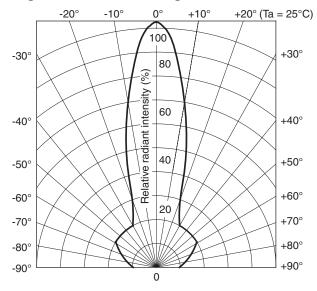


Fig. 10 Radiation Diagram



Angular displacement θ



#### ■ Design Considerations

#### **Design Guidelines**

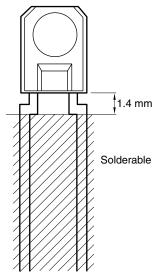
- 1. Allow for natural degradation of the LED as a result of long continuous operation. This part will have 50% degradation in output after 5 years of continuous use.
- 2. This product is not designed to be electromagnetic- and ionized-particle-radiation resistant.

#### ■ Manufacturing Guidelines

#### **Cleaning Instructions**

- 1. Confirm this device's resistance to process chemicals before use, as certain process chemicals may affect the optical characteristics.
- 2. Solvent cleaning: Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.
- Ultrasonic cleaning: The effect upon devices varies due to cleaning bath size, ultrasonic power output, cleaning time, PCB size and device mounting circumstances. Sharp recommends testing using actual production conditions to confirm the harmlessness of the ultrasonic cleaning methods.
- 4. Recommended solvent materials: Ethyl alcohol, Methyl alcohol, and Isopropyl alcohol.

Fig. 11 Soldering Area



## ■ Packing Specifications

- Parts are packed in a vinyl bag, at an average quantity of 1,000 pieces per bag.
- 2. Bags are secured in a box as shown in illustration on page 8.
- 3. Product mass: 0.09 g (approx.)



#### ■ Presence of ODCs (RoHS Compliance)

This product shall not contain the following materials, and they are not used in the production process for this product:

• Regulated substances: CFCs, Halon, Carbon tetrachloride, 1,1,1-Trichloroethane (Methylchloroform). Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

- Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).
- Content information about the six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (Chinese: 电子信息产品污染控制管理办法)

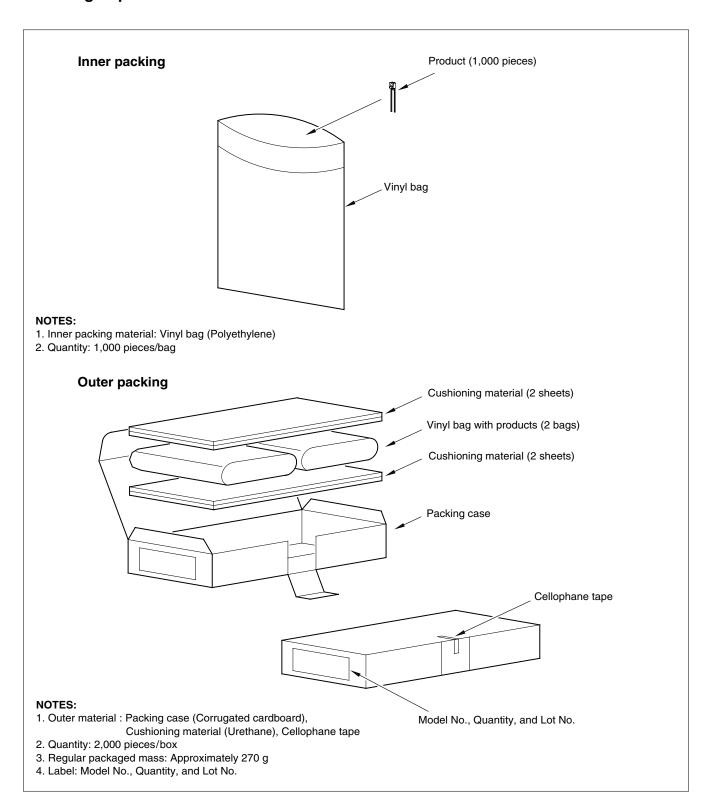
|                         | Toxic and Hazdardous Substances |              |              |   | ınces                          |                                       |
|-------------------------|---------------------------------|--------------|--------------|---|--------------------------------|---------------------------------------|
| Category                | Lead (Pb)                       | mercury (Hg) | Cadmium (Cd) | Hexavalent chromiun (Cr <sup>6+</sup> ) | Polybrominated biphenyls (PBB) | Polybrominated diphenyl ethers (PBDE) |
| Infrared Emitting Diode | ✓                               | ✓            | ✓            | ✓                                       | ✓                              | ✓                                     |

NOTE:  $\checkmark$  indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006 standard.

Sheet No.: D1-A01101EN



## **■** Package Specification





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